

APT8DQ60KG*

600V 8A

*G Denotes RoHS Compliant, Pb Free Terminal Finish.

ULTRAFAST SOFT RECOVERY RECTIFIER DIODE

PRODUCT APPLICATIONS

- Anti-Parallel Diode -Switchmode Power Supply -Inverters
- Free Wheeling Diode -Motor Controllers -Converters -Inverters
- Snubber Diode

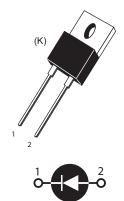
• PFC

PRODUCT FEATURES

- Ultrafast Recovery Times
- Soft Recovery Characteristics
- · Popular TO-220 Package or Surface Mount D² PAK Package
- Low Forward Voltage
- · Low Leakage Current
- Avalanche Energy Rated

PRODUCT BENEFITS

- Low Losses
- Low Noise Switching
- Cooler Operation
- · Higher Reliability Systems
- Increased System Power Density



1 - Cathode 2 - Anode

Back of Case - Cathode

MAXIMUM RATINGS

All Ratings: $T_{C} = 25^{\circ}C$ unless otherwise specified. APT8DQ60K(G) **Characteristic / Test Conditions** UNIT Symbol V_R Maximum D.C. Reverse Voltage V_{RRM} Maximum Peak Repetitive Reverse Voltage 600 Volts V_{RWM} Maximum Working Peak Reverse Voltage Maximum Average Forward Current ($T_{C} = 128^{\circ}C$, Duty Cycle = 0.5) 8 I_{F(AV)} RMS Forward Current (Square wave, 50% duty) 16 Amps I_{F(RMS)} Non-Repetitive Forward Surge Current ($T_1 = 45^{\circ}C$, 8.3ms) 110 I_{FSM} $\mathsf{E}_{\mathsf{AVL}}$ 20 Avalanche Energy (1A, 40mH) mJ -55 to 175 T_J,T_{STG} Operating and StorageTemperature Range °C TL 300 Lead Temperature for 10 Sec.

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions		MIN	TYP	МАХ	UNIT
V _F	Forward Voltage	I _F = 8A		2.0	2.4	
		I _F = 16A		2.5		Volts
		I _F = 8A, T _J = 125°C		1.5		
I _{RM}	Maximum Reverse Leakage Current	V _R = 600V			25	μA
		V _R = 600V, T _J = 125°C			500	
C _T	Junction Capacitance, V _R = 200V			16		pF

DYNAMIC CHARACTERISTICS

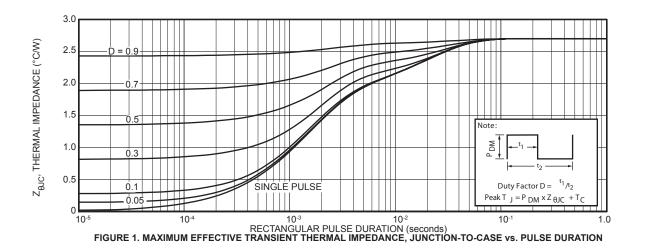
APT8DQ60K(G)

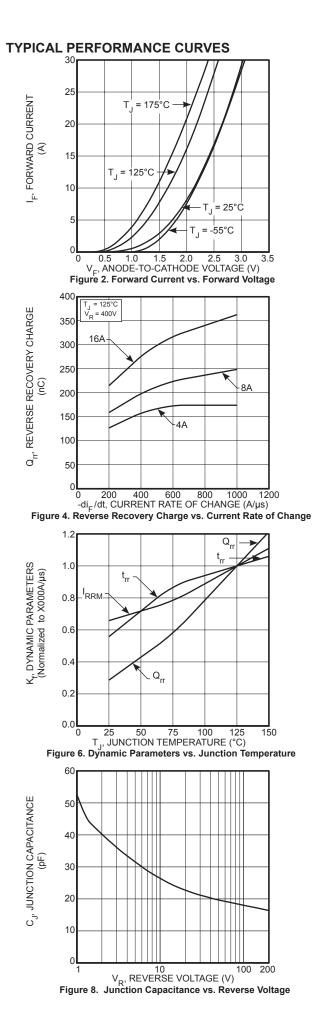
Symbol	Characteristic	Test Conditions	MIN	ТҮР	MAX	UNIT
t _{rr}	Reverse Recovery Time $I_F = 1A$, $di_F/dt = -100A/\mu s$, $V_R = 30V$, $T_J = 25^{\circ}C$		-	14		ns
t _{rr}	Reverse Recovery Time	I _F = 8A, di _F /dt = -200A/μs V _R = 400V, T _C = 25°C	-	19		115
Q _{rr}	Reverse Recovery Charge		-	17		nC
I _{RRM}	Maximum Reverse Recovery Current		-	2	-	Amps
t _{rr}	Reverse Recovery Time	I _F = 8A, di _F /dt = -200A/μs V _R = 400V, T _C = 125°C	-	90		ns
Q _{rr}	Reverse Recovery Charge		-	160		nC
I _{RRM}	Maximum Reverse Recovery Current		-	3	-	Amps
t _{rr}	Reverse Recovery Time	I _F = 8A, di _F /dt = -1000A/μs V _R = 400V, T _C = 125°C	-	43		ns
Q _{rr}	Reverse Recovery Charge		-	250		nC
I _{RRM}	Maximum Reverse Recovery Current		-	11		Amps

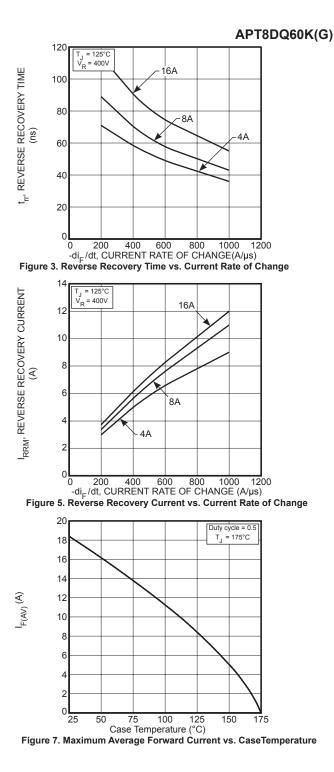
THERMAL AND MECHANICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT
R _{θJC}	Junction-to-Case Thermal Resistance			2.7	°C/W
W _T	Package Weight		0.07		οz
			1.9		g
Torque	Maximum Mounting Torque			10	lb•in
				1.1	N•m

Microsemi reserves the right to change, without notice, the specifications and information contained herein.







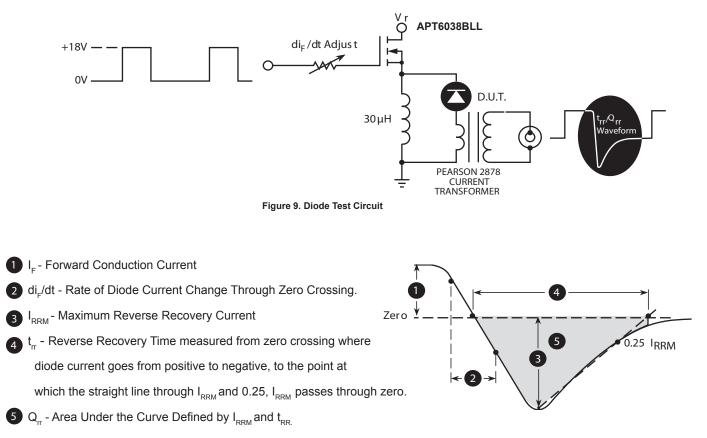
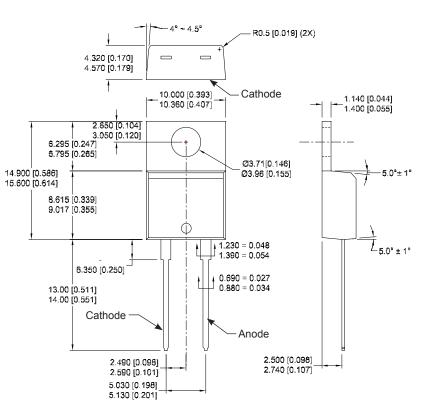


Figure 10. Diode Reverse Recovery Waveform Definition



TO-220 (K) Package Outline e3 100% Sn

Dimensions in millimeters and [inches]

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